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**Question Paper Code : 80134**

B.E./B.Tech. DEGREE EXAMINATIONS, APRIL/MAY 2019.

Fourth Semester

Electrical and Electronics Engineering

EE 8451 — LINEAR INTEGRATED CIRCUITS AND APPLICATIONS

(Common to Electronics and Instrumentation Engineering/Instrumentation and Control Engineering)

(Regulation 2017)

Time : Three hours

Maximum : 100 marks

Answer ALL questions.

PART A — (10 × 2 = 20 marks)

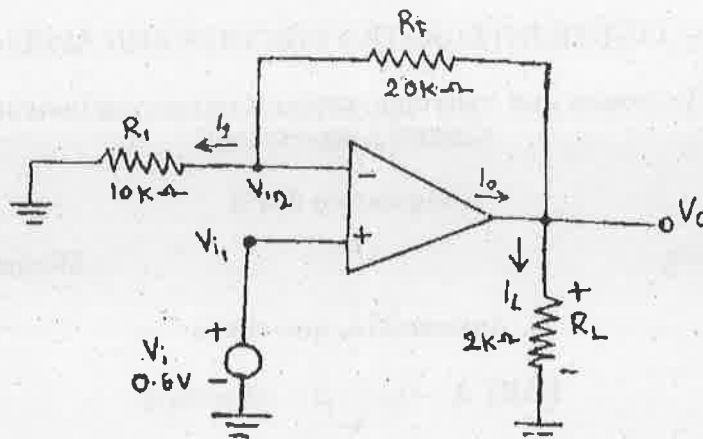
1. Define the term Encapsulation.
2. List the advantages of thin film resistors.
3. Give the various types of frequency compensation.
4. The output voltage of a certain op-amp circuit changes by 20 V in 4  $\mu$ s. What is its slew rate?
5. List the four requirements of an Instrumentation amplifier.
6. Give the circuit using Op-amp for a first order low-pass filter with variable gain.
7. Determine the frequency of oscillations, if the duty cycle  $D = 20\%$  and the ON period  $T_{on} = 2$  ms.
8. Draw the output of a missing pulse detector.
9. What is a Load cell?
10. Give the seven output voltage options available in fixed voltage series regulator.

PART B — (5 × 13 = 65 marks)

11. (a) (i) Explain the fabrication technique of FET in detail. (7)  
 (ii) Discuss the Photolithographic process with necessary illustrations. (6)

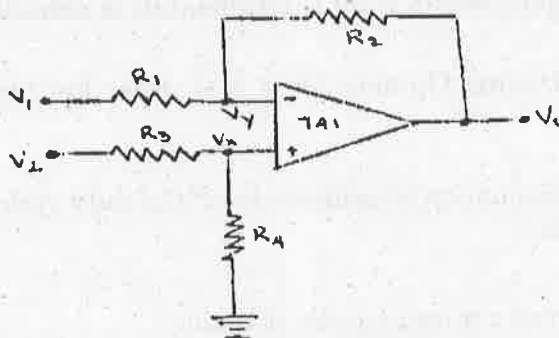
Or

- (b) Describe the methods in Thin and Thick film technology.
12. (a) For the given non-inverting amplifier shown in figure below, determine (i)  $A_v$ ; (ii)  $V_o$ ; (iii)  $I_L$  and (iv)  $I_o$ .



Or

- (b) Explain with neat circuit expressions about the working of (i) Inverting Amplifiers (ii) Integrating circuit and derive the gain. (6 + 7)
13. (a) Find the following for the given Op-amp differential amplifier : (i) The gain of the amplifier (ii) The input resistance (iii) Output voltage, when the inputs are  $1\sin(2000t)$  V and  $1.2\sin(2000t)$  and the  $R_1 = R_3 = 1.2$  k $\Omega$  and  $R_2 = R_4 = 22$  k $\Omega$ .



Or

- (b) Discuss the application of Op-amps, with necessary equivalent circuits and expressions for (i) D/A converter (ii) A/D converter.

14. (a) In detail, explain the functional block and characteristics of 555 Timer with its PWM application.

Or

- (b) Discuss the ICC 566 as a voltage controlled oscillator with necessary illustrations.

15. (a) Explain the Fixed voltage regulator and its applications.

Or

- (b) Explain the function of SMPS with neat waveforms and schema.

PART C — (1 × 15 = 15 marks)

16. (a) With neat figures explain the design of a circuit for performing (i) square wave generation (ii) sweep signal conversion (iii) clamped signal output. (15)

Or

- (b) Determine the output frequency  $f_0$ , lock range  $\Delta f_L$  and capture range  $\Delta f_C$  of IC 565. Assume  $R_1 = 15 \text{ k}\Omega$ ,  $C_1 = 0.01 \mu\text{F}$ ,  $C = 1 \mu\text{F}$  and the supply voltage is +12 V. (15)

